

# SN54ALS805A, SN54AS805B, SN74ALS805A, SN74AS805B HEX 2-INPUT NOR DRIVERS

SDAS023C – DECEMBER 1982 – REVISED JANUARY 1995

- High Capacitive-Drive Capability
- 'ALS805A Has Typical Delay Time of 4.2 ns ( $C_L = 50$  pF) and Typical Power Dissipation of 4.2 mW Per Gate
- 'AS805B Has Typical Delay Time of 2.6 ns ( $C_L = 50$  pF) and Typical Power Dissipation of 12 mW Per Gate
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

## description

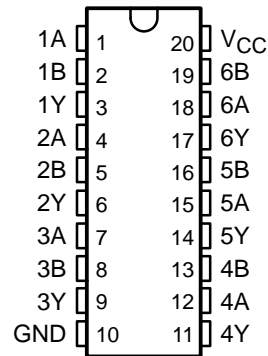
These devices contain six independent 2-input NOR drivers. They perform the Boolean functions  $Y = \overline{A + B}$  or  $Y = \overline{A} \cdot \overline{B}$  in positive logic.

The SN54ALS805A and SN54AS805B are characterized for operation over the full military temperature range of  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ . The SN74ALS805A and SN74AS805B are characterized for operation from  $0^\circ\text{C}$  to  $70^\circ\text{C}$ .

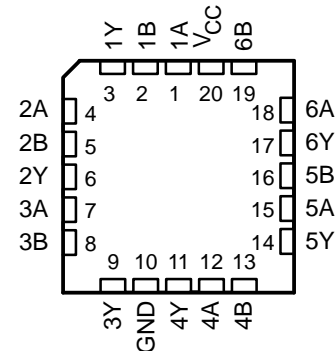
FUNCTION TABLE  
(each driver)

| INPUTS |   | OUTPUT<br>Y |
|--------|---|-------------|
| A      | B |             |
| H      | X | L           |
| X      | H | L           |
| L      | L | H           |

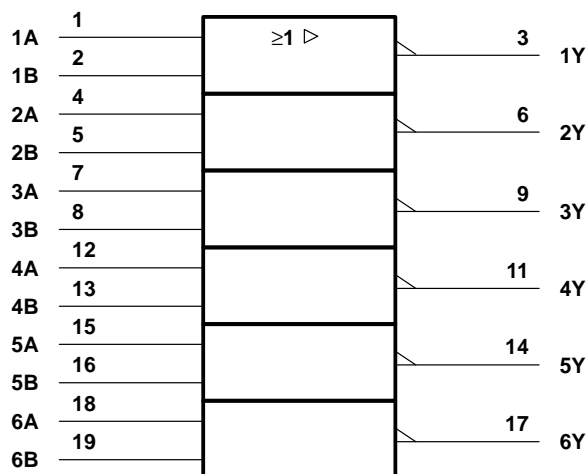
SN54ALS805A, SN54AS805B ... J PACKAGE  
SN74ALS805A, SN74AS805B ... DW OR N PACKAGE  
(TOP VIEW)



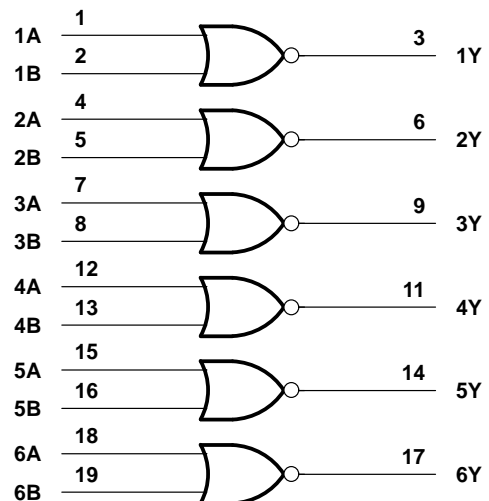
SN54ALS805A, SN54AS805B ... FK PACKAGE  
(TOP VIEW)



## logic symbol†



## logic diagram (positive logic)



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

# SN54ALS805A, SN54AS805B, SN74ALS805A, SN74AS805B

## HEX 2-INPUT NOR DRIVERS

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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

|   |                |
|---|----------------|
| Supply voltage, $V_{CC}$                                  | 7 V            |
| Input voltage, $V_I$                                      | 7 V            |
| Operating free-air temperature range, $T_A$ : SN54ALS805A | –55°C to 125°C |
| SN74ALS805A   | 0°C to 70°C    |
| Storage temperature range                                 | –65°C to 150°C |

<sup>†</sup> Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### recommended operating conditions

|          |                                | SN54ALS805A |     |     | SN74ALS805A |     |     | UNIT |
|----------|--------------------------------|-------------|-----|-----|-------------|-----|-----|------|
|          |                                | MIN         | NOM | MAX | MIN         | NOM | MAX |      |
| $V_{CC}$ | Supply voltage                 | 4.5         | 5   | 5.5 | 4.5         | 5   | 5.5 | V    |
| $V_{IH}$ | High-level input voltage       | 2           |     |     | 2           |     |     | V    |
| $V_{IL}$ | Low-level input voltage        |             |     | 0.7 |             |     | 0.8 | V    |
| $I_{OH}$ | High-level output current      |             |     | –12 |             |     | –15 | mA   |
| $I_{OL}$ | Low-level output current       |             |     | 12  |             |     | 24  | mA   |
| $T_A$    | Operating free-air temperature | –55         |     | 125 | 0           |     | 70  | °C   |

### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER    | TEST CONDITIONS            |                    | SN54ALS805A  |                  |      | SN74ALS805A  |                  |      | UNIT |
|--------------|----------------------------|--------------------|--------------|------------------|------|--------------|------------------|------|------|
|              |                            |                    | MIN          | TYP <sup>‡</sup> | MAX  | MIN          | TYP <sup>‡</sup> | MAX  |      |
| $V_{IK}$     | $V_{CC} = 4.5$ V,          | $I_I = -18$ mA     |              |                  | –1.2 |              |                  | –1.2 | V    |
| $V_{OH}$     | $V_{CC} = 4.5$ V to 5.5 V, | $I_{OH} = -0.4$ mA | $V_{CC} - 2$ |                  |      | $V_{CC} - 2$ |                  |      | V    |
|              | $V_{CC} = 4.5$ V           | $I_{OH} = -3$ mA   | 2.4          | 3.2              |      | 2.4          | 3.2              |      |      |
|              |                            | $I_{OH} = -12$ mA  | 2            |                  |      |              |                  |      |      |
|              |                            | $I_{OH} = -15$ mA  |              |                  |      | 2            |                  |      |      |
| $V_{OL}$     | $V_{CC} = 4.5$ V           | $I_{OL} = 12$ mA   |              | 0.25             | 0.4  |              | 0.25             | 0.4  | V    |
|              |                            | $I_{OL} = 24$ mA   |              |                  |      |              | 0.35             | 0.5  |      |
| $I_I$        | $V_{CC} = 5.5$ V,          | $V_I = 7$ V        |              |                  | 0.1  |              |                  | 0.1  | mA   |
| $I_{IH}$     | $V_{CC} = 5.5$ V,          | $V_I = 2.7$ V      |              |                  | 20   |              |                  | 20   | μA   |
| $I_{IL}$     | $V_{CC} = 5.5$ V,          | $V_I = 0.4$ V      |              |                  | –0.1 |              |                  | –0.1 | mA   |
| $I_{O}^{\S}$ | $V_{CC} = 5.5$ V,          | $V_O = 2.25$ V     | –20          |                  | –112 | –30          |                  | –112 | mA   |
| $I_{CCH}$    | $V_{CC} = 5.5$ V,          | $V_I = 0$          |              | 2                | 4    |              | 2                | 4    | mA   |
| $I_{CCL}$    | $V_{CC} = 5.5$ V,          | $V_I = 4.5$ V      |              | 8                | 14   |              | 8                | 14   | mA   |

<sup>‡</sup> All typical values are at  $V_{CC} = 5$  V,  $T_A = 25^\circ\text{C}$ .

<sup>\S</sup> The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current,  $I_{OS}$ .



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# SN54ALS805A, SN54AS805B, SN74ALS805A, SN74AS805B HEX 2-INPUT NOR DRIVERS

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## switching characteristics (see Figure 1)

| PARAMETER        | FROM<br>(INPUT) | TO<br>(OUTPUT) | V <sub>CC</sub> = 4.5 V to 5.5 V,<br>C <sub>L</sub> = 50 pF,<br>R <sub>L</sub> = 500 Ω,<br>T <sub>A</sub> = MIN to MAX† |     |             |     | UNIT |
|------------------|-----------------|----------------|---|-----|-------------|-----|------|
|                  |                 |                | SN54ALS805A   |     | SN74ALS805A |     |      |
|                  |                 |                | MIN   | MAX | MIN         | MAX |      |
| t <sub>PLH</sub> | A or B          | Y              | 1   | 12  | 2           | 7   | ns   |
| t <sub>PHL</sub> |                 |                | 1   | 9   | 2           | 8   |      |

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

|   |                |
|---|----------------|
| Supply voltage, V <sub>CC</sub>                                   | 7 V            |
| Input voltage, V <sub>I</sub>                                     | 7 V            |
| Operating free-air temperature range, T <sub>A</sub> : SN54AS805B | –55°C to 125°C |
| SN74AS805B  | 0°C to 70°C    |
| Storage temperature range   | –65°C to 150°C |

‡ Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## recommended operating conditions§

|                 |                                | SN54AS805B |     |     | SN74AS805B |     |     | UNIT |
|-----------------|--------------------------------|------------|-----|-----|------------|-----|-----|------|
|                 |                                | MIN        | NOM | MAX | MIN        | NOM | MAX |      |
| V <sub>CC</sub> | Supply voltage                 | 4.5        | 5   | 5.5 | 4.5        | 5   | 5.5 | V    |
| V <sub>IH</sub> | High-level input voltage       | 2          |     |     | 2          |     |     | V    |
| V <sub>IL</sub> | Low-level input voltage        |            |     | 0.8 |            |     | 0.8 | V    |
| I <sub>OH</sub> | High-level output current      |            |     | –40 |            |     | –48 | mA   |
| I <sub>OL</sub> | Low-level output current       |            |     | 40  |            |     | 48  | mA   |
| T <sub>A</sub>  | Operating free-air temperature | –55        |     | 125 | 0          |     | 70  | °C   |

§ These high sink- or source-current devices are not recommended for use above 40 MHz.

# SN54ALS805A, SN54AS805B, SN74ALS805A, SN74AS805B

## HEX 2-INPUT NOR DRIVERS

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**electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)**

| PARAMETER                   | TEST CONDITIONS   |                          | SN54AS805B          |      |      | SN74AS805B          |      |      | UNIT |
|-----------------------------|---|--------------------------|---------------------|------|------|---------------------|------|------|------|
|                             |   |                          | MIN                 | TYP† | MAX  | MIN                 | TYP† | MAX  |      |
| V <sub>IK</sub>             | V <sub>CC</sub> = 4.5 V, I <sub>I</sub> = −18 mA          |                          | −1.2                |      |      | −1.2                |      |      | V    |
| V <sub>OH</sub>             | V <sub>CC</sub> = 4.5 V to 5.5 V, I <sub>OH</sub> = −2 mA |                          | V <sub>CC</sub> − 2 |      |      | V <sub>CC</sub> − 2 |      |      | V    |
|                             | V <sub>CC</sub> = 4.5 V                                   | I <sub>OH</sub> = −3 mA  | 2.4                 | 3.2  |      | 2.4                 | 3.2  |      |      |
|                             |   | I <sub>OH</sub> = −40 mA | 2                   |      |      |                     |      |      |      |
|                             |   | I <sub>OH</sub> = −48 mA |                     |      |      | 2                   |      |      |      |
| V <sub>OL</sub>             | V <sub>CC</sub> = 4.5 V                                   | I <sub>OL</sub> = 40 mA  | 0.25                | 0.5  |      |                     |      | V    |      |
|                             |   | I <sub>OL</sub> = 48 mA  |                     |      |      | 0.35                | 0.5  |      |      |
| I <sub>I</sub>              | V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 7 V             |                          | 0.1                 |      |      | 0.1                 |      |      | mA   |
| I <sub>IH</sub>             | V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 2.7 V           |                          | 20                  |      |      | 20                  |      |      | μA   |
| I <sub>IL</sub>             | V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0.4 V           |                          | −0.5                |      |      | −0.5                |      |      | mA   |
| I <sub>O</sub> <sup>‡</sup> | V <sub>CC</sub> = 5.5 V, V <sub>O</sub> = 2.25 V          |                          | −50                 |      | −200 | −50                 |      | −200 | mA   |
| I <sub>CC</sub> H           | V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0               |                          | 6.5                 | 10   |      | 6.5                 | 10   |      | mA   |
| I <sub>CC</sub> L           | V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 4.5 V           |                          | 20                  | 32   |      | 20                  | 32   |      | mA   |

† All typical values are at  $V_{CC} = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ .

‡ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current,  $I_{OS}$ .

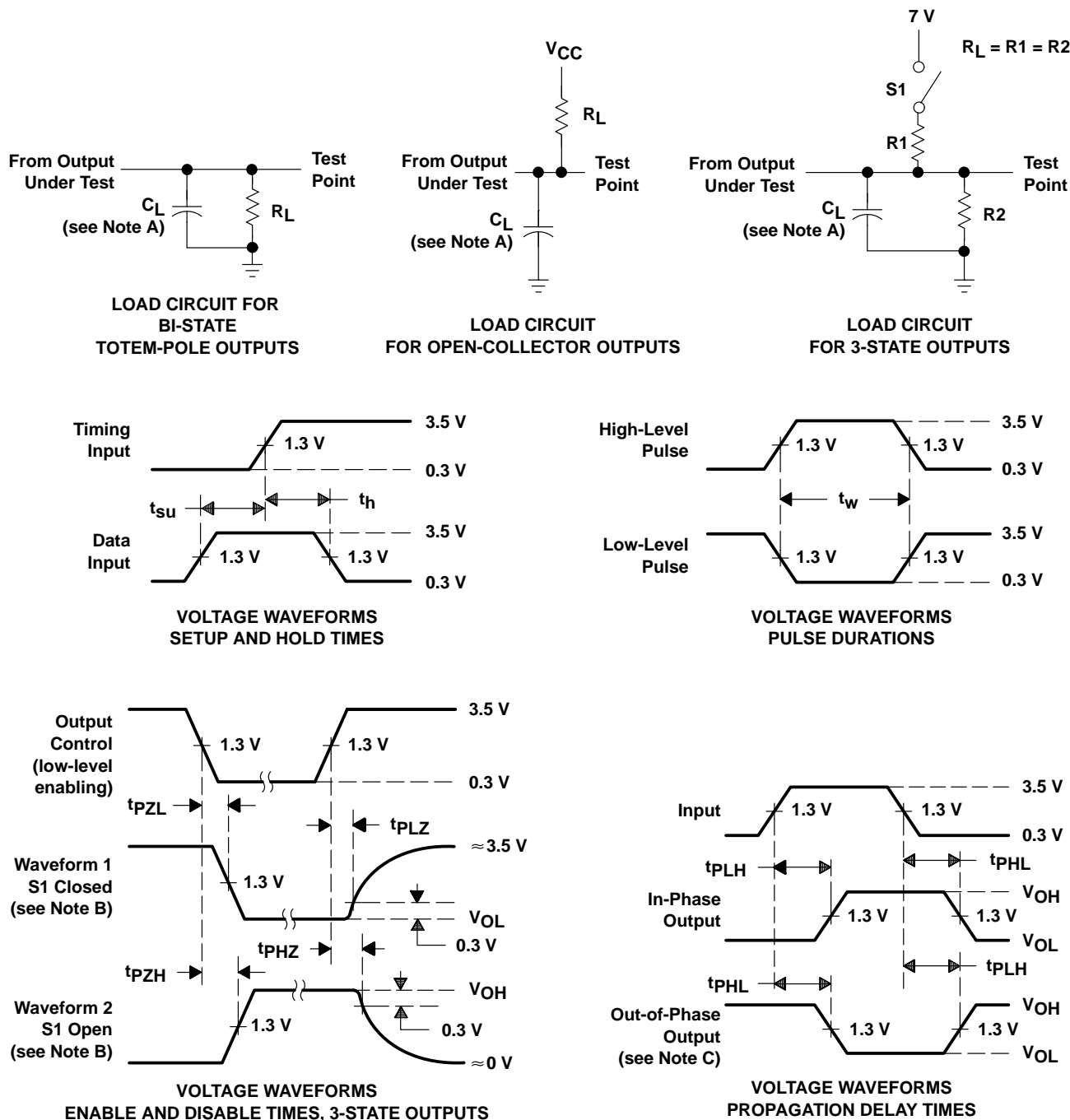
### switching characteristics (see Figure 1)

| PARAMETER        | FROM<br>(INPUT) | TO<br>(OUTPUT) | V <sub>CC</sub> = 4.5 V to 5.5 V,<br>C <sub>L</sub> = 50 pF,<br>R <sub>L</sub> = 500 Ω,<br>T <sub>A</sub> = MIN to MAX§ |     |            |     | UNIT |
|------------------|-----------------|----------------|---|-----|------------|-----|------|
|                  |                 |                | SN54AS805B  |     | SN74AS805B |     |      |
|                  |                 |                | MIN   | MAX | MIN        | MAX |      |
| t <sub>PLH</sub> | A or B          | Y              | 1   | 4.8 | 1          | 4.3 | ns   |
| t <sub>PHL</sub> |                 |                | 1   | 4.8 | 1          | 4.3 |      |

§ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.



PARAMETER MEASUREMENT INFORMATION  
SERIES 54ALS/74ALS AND 54AS/74AS DEVICES



- NOTES: A.  $C_L$  includes probe and jig capacitance.  
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.  
C. When measuring propagation delay items of 3-state outputs, switch S1 is open.  
D. All input pulses have the following characteristics:  $PRR \leq 1$  MHz,  $t_r = t_f = 2$  ns, duty cycle = 50%.  
E. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms

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